

September 2011

# FAN5400/FAN5401/FAN5402/FAN5403/FAN5404/FAN5405 USB-Compliant Single-Cell Li-Ion Switching Charger with USB-OTG Boost Regulator

### **Features**

- Fully Integrated, High-Efficiency Charger for Single-Cell Li-Ion and Li-Polymer Battery Packs
- Faster Charging than Linear
- Charge Voltage Accuracy: ±0.5% at 25°C

±1% from 0 to 125°C

- ±5% Input Current Regulation Accuracy
- ±5% Charge Current Regulation Accuracy
- 20V Absolute Maximum Input Voltage
- 6V Maximum Input Operating Voltage
- 1.25A Maximum Charge Rate
- Programmable through High-Speed I<sup>2</sup>C Interface (3.4Mb/s) with Fast Mode Plus Compatibility
  - Input Current
  - Fast-Charge / Termination Current
  - Charger Voltage
  - Termination Enable
- 3MHz Synchronous Buck PWM Controller with Wide Duty Cycle Range
- Small Footprint 1µH External Inductor
- Safety Timer with Reset Control
- 1.8V Regulated Output from VBUS for Auxiliary Circuits
- Weak Input Sources Accommodated by Reducing Charging Current to Maintain Minimum VBUS Voltage
- Low Reverse Leakage to Prevent Battery Drain to VBUS
- 5V, 300mA Boost Mode for USB OTG for 2.5 to 4.5V Battery Input

## **Applications**

- Cell Phones, Smart Phones, PDAs
- Tablet, Portable Media Players
- Gaming Device, Digital Cameras

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## Description

The FAN5400 family (FAN540X) combines a highly integrated switch-mode charger, to minimize single-cell Lithium-ion (Li-ion) charging time from a USB power source, and a boost regulator to power a USB peripheral from the battery.

The charging parameters and operating modes are programmable through an I<sup>2</sup>C Interface that operates up to 3.4Mbps. The charger and boost regulator circuits switch at 3MHz to minimize the size of external passive components.

The FAN540X provides battery charging in three phases: conditioning, constant current, and constant voltage.

To ensure USB compliance and minimize charging time, the input current is limited to the value set through the  $I^2C$  host. Charge termination is determined by a programmable minimum current level. A safety timer with reset control provides a safety backup for the  $I^2C$  host.

The integrated circuit (IC) automatically restarts the charge cycle when the battery falls below an internal threshold. If the input source is removed, the IC enters a high-impedance mode with leakage from the battery to the input prevented. Charge status is reported back to the host through the I<sup>2</sup>C port. Charge current is reduced when the die temperature reaches 120°C.

The FAN540X can operate as a boost regulator on command from the system. The boost regulator includes a soft-start that limits inrush current from the battery.

The FAN540X is available in a 1.96 x 1.87mm, 20-bump, 0.4mm pitch WLCSP package.

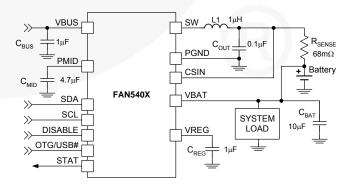


Figure 1. Typical Application (FAN5403-05 Pin Out)

## **Ordering Information**

Part Number	Temperature Range	Package	PN Bits: IC_INFO[4:3]	Packing Method
FAN5400UCX	-40 to 85°C		01	Tape and Reel
FAN5401UCX	-40 to 85°C	20- Bump, Wafer- Level Chip-Scale	00	Tape and Reel
FAN5402UCX	-40 to 85°C	Package (WLCSP),	01	Tape and Reel
FAN5403UCX	-40 to 85°C	0.4mm Pitch,	10	Tape and Reel
FAN5404UCX	-40 to 85°C	Estimated Size: 1.96 x 1.87mm	11	Tape and Reel
FAN5405UCX	-40 to 85°C		10	Tape and Reel

**Table 1. Feature Comparison Summary** 

Part Number	PN Bits: REG3[4:3]	Slave Address	Automatic Charge	Special Charger <sup>(1)</sup>	Safety Limits	Battery Absent Behavior	E2 Pin	VREG (E3 Pin)
FAN5400	01	1101011	Yes	No	No	OFF	AUXPWR	
FAN5401	00	1101011	No	No	No	OFF	(Connect to	PMID
FAN5402	01	1101011	Yes	No	No	ON	VBAT)	
FAN5403	10	1101011	Yes	Yes	Yes	OFF		
FAN5404	11	1101011	No	Yes	Yes	OFF	DISABLE	1.8V
FAN5405	10	1101010	Yes	Yes	Yes	ON		

#### Note:

**Table 2. Recommended External Components** 

Component	Description	Vendor	Parameter	Тур.	Unit
L1	1LL 200/ 1.2A 2016	Murata: LQM2MPN1R0M	L	1.0	μН
LI	1μH, 20%, 1.3A, 2016	or Equivalent	DCR (Series R)	85	mΩ
Сват	10μF, 20%, 6.3V, X5R, 0603	Murata: GRM188R60J106M TDK: C1608X5R0J106M	С	10	μF
C <sub>MID</sub>	4.7μF, 10%, 6.3V, X5R, 0603	Murata: GRM188R60J475K TDK: C1608X5R0J475K	C <sup>(2)</sup>	4.7	μF
C <sub>BUS</sub>	1.0μF, 10%, 25V, X5R, 0603	Murata GRM188R61E105K TDK:C1608X5R1E105M	С	1.0	μF

#### Note:

2. 6.3V rating is sufficient for  $C_{\text{MID}}$  since PMID is protected from over-voltage surges on VBUS by Q3 (Figure 3).

<sup>1.</sup> Special charger is a current limited charger that is not a USB compliant source.

## **Block Diagram**

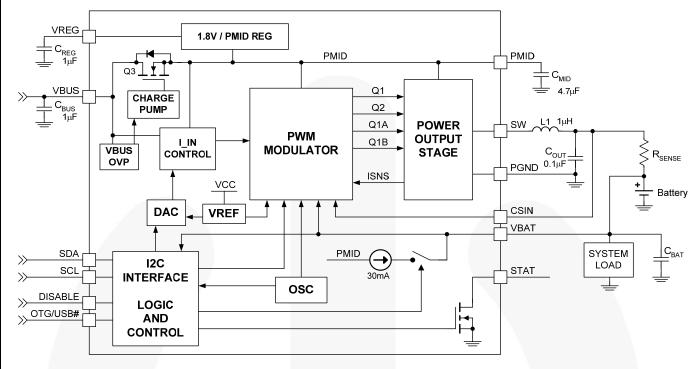


Figure 2. IC and System Block Diagram

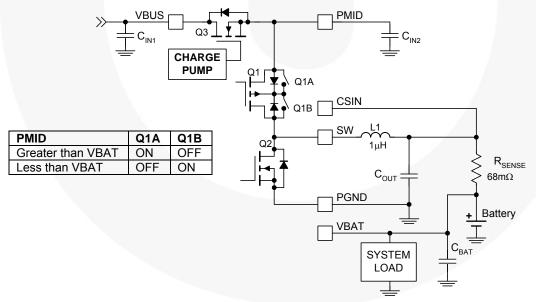
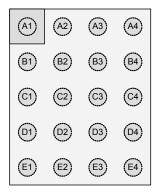
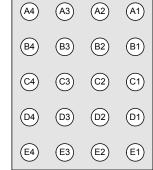


Figure 3. Power Stage

## **Pin Configuration**





(A1)

**Top View** 

**Bottom View** 

Figure 4. WLCSP-20 Pin Assignments

## **Pin Definitions**

Pin#	Name	Part #	Description
A1, A2	VBUS	ALL	Charger Input Voltage and USB-OTG output voltage. Bypass with a $1\mu F$ capacitor to PGND.
A3	NC	ALL	No Connect. No external connection is made between this pin and the IC's internal circuitry.
A4	SCL	ALL	I <sup>2</sup> C Interface Serial Clock. This pin should not be left floating.
B1-B3	PMID	ALL	<b>Power Input Voltage</b> . Power input to the charger regulator, bypass point for the input current sense, and high-voltage input switch. Bypass with a minimum of $4.7\mu F$ , $6.3V$ capacitor to PGND.
B4	SDA	ALL	I <sup>2</sup> C Interface Serial Data. This pin should not be left floating.
C1-C3	SW	ALL	Switching Node. Connect to output inductor.
C4	STAT	ALL	<b>Status</b> . Open-drain output indicating charge status. The IC pulls this pin LOW when charge is in process.
D1-D3	PGND	ALL	<b>Power Ground</b> . Power return for gate drive and power transistors. The connection from this pin to the bottom of $C_{\text{MID}}$ should be as short as possible.
D4	OTG	ALL	<b>On-The-Go</b> . Enables boost regulator in conjunction with OTG_EN and OTG_PL bits (see Table 16). On VBUS Power-On Reset (POR), this pin sets the input current limit for t <sub>15MIN</sub> charging.
E1	CSIN	ALL	<b>Current-Sense Input</b> . Connect to the sense resistor in series with the battery. The IC uses this node to sense current into the battery. Bypass this pin with a 0.1µF capacitor to PGND.
E2	AUXPWR	FAN5400, FAN5401, FAN5402	Auxiliary Power. Connect to the battery pack to provide IC power during High-Impedance Mode. Bypass with a $1\mu F$ capacitor to PGND.
E2	DISABLE	FAN5403, FAN5404, FAN5405	<b>Charge Disable</b> . If this pin is HIGH, charging is disabled. When LOW, charging is controlled by the I <sup>2</sup> C registers. When this pin is HIGH, the 15-minute timer is reset. This pin does not affect the 32-second timer.
E3	VREG	ALL	<b>Regulator Output</b> . Connect to a $1\mu F$ capacitor to PGND. This pin can supply up to 2mA of DC load current. For FAN5400-FAN5402, the output voltage is PMID, which is limited to 6.5V. For FAN5403-FAN5405, the output voltage is regulated to 1.8V.
E4	VBAT	ALL	Battery Voltage. Connect to the positive (+) terminal of the battery pack. Bypass with a 0.1µF capacitor to PGND if the battery is connected through long leads.

## **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol		Parameter	Min.	Max.	Unit
\/	VBUS Voltage	Continuous	-1.4	20.0	V
$V_{BUS}$	VB03 Vollage	Pulsed, 100ms Maximum Non-Repetitive	-2.0	20.0	V
V <sub>STAT</sub>	STAT Voltage		-0.3	16.0	V
Vı	PMID Voltage			7.0	V
VI	SW, CSIN, VBAT, AUXPWR,	DISABLE Voltage	-0.3	7.0	]
Vo	Voltage on Other Pins		-0.3	6.5 <sup>(3)</sup>	V
$\frac{\text{dV}_{\text{BUS}}}{\text{dt}}$	Maximum VBUS Slope above	e 5.5V when Boost or Charger are Active		4	V/μs
ESD	Electrostatic Discharge	Human Body Model per JESD22-A114	20	000	V
ESD	Protection Level	Charged Device Model per JESD22-C101	5	00	] V
TJ	Junction Temperature		-40	+150	°C
T <sub>STG</sub>	Storage Temperature		-65	+150	°C
TL	Lead Soldering Temperature	10 Seconds		+260	°C

#### Note:

3. Lesser of 6.5V or  $V_1 + 0.3V$ .

## **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter			Max.	Units
$V_{BUS}$	Supply Voltage		4	6	V
V <sub>BAT(MAX)</sub>	Maximum Battery Voltage when Boost enabled			4.5	V
_ dV <sub>BUS</sub>	Negative VBUS Slew Rate during VBUS Short Circuit,	T <sub>A</sub> ≤ 60°C		4	\// a
dt	$C_{MID} \leq 4.7 \mu F$ , see VBUS Short While Charging	T <sub>A</sub> ≥ 60°C		2	V/μs
T <sub>A</sub>	Ambient Temperature		-30	+85	°C
TJ	Junction Temperature (see Thermal Regulation and Prote	ction section)	-30	+120	°C

## Thermal Properties

Junction-to-ambient thermal resistance is a function of application and board layout. This data is measured with four-layer 2s2p boards in accordance to JEDEC standard JESD51. Special attention must be paid not to exceed junction temperature  $T_{J(max)}$  at a given ambient temperature  $T_A$ . For measured data, see Table 11.

Symbol	Parameter	Typical	Units
$\theta_{JA}$	Junction-to-Ambient Thermal Resistance	60	°C/W
$\theta_{JB}$	Junction-to-PCB Thermal Resistance	20	°C/W

## **Electrical Specifications**

Unless otherwise specified: according to the circuit of Figure 1; recommended operating temperature range for  $T_J$  and  $T_A$ ;  $V_{BUS}$ =5.0V;  $HZ_MODE$ ;  $OPA_MODE$ =0; (Charge Mode); SCL, SDA, OTG=0 or 1.8V; and typical values are for  $T_J$ =25°C.

Symbol	Parameter	Condi	tions	Min.	Тур.	Max.	Units
Power Supp	lies						· 
		$V_{BUS} > V_{BUS(min)}$ , PW	M Switching		10		mA
$I_{VBUS}$	VBUS Current	V <sub>BUS</sub> > V <sub>BUS(min)</sub> ; PWM Enabled, Not Switching (Battery OVP Condition); I_IN Setting=100mA			2.5		mA
		$0^{\circ}\text{C} < \text{T}_{\text{J}} < 85^{\circ}\text{C}, \text{ Hz}$ $\text{V}_{\text{BAT}} < \text{V}_{\text{LOWV}}, 32\text{S} \text{ N}$			63	90	μА
$I_{LKG}$	VBAT to VBUS Leakage Current	0°C < T <sub>J</sub> < 85°C, HZ V <sub>BAT</sub> =4.2V, V <sub>BUS</sub> =0V			0.2	5.0	μА
l	Battery Discharge Current in High-	0°C < T <sub>J</sub> < 85°C, HZ V <sub>BAT</sub> =4.2V	Z_MODE=1,			20	
I <sub>BAT</sub>	Impedance Mode	FAN5403-05, DISAB 0°C < T <sub>J</sub> < 85°C, V <sub>B</sub>				10	μΑ
Charger Vol	tage Regulation						
	Charge Voltage Range			3.5		4.4	
$V_{OREG}$	Charge Voltage Assurage	T <sub>A</sub> =25°C		-0.5%		+0.5%	V
	Charge Voltage Accuracy	T <sub>J</sub> =0 to 125°C		-1%		+1%	
Charging Cเ	urrent Regulation						
	Output Charge Current Range	V <sub>LOWV</sub> < V <sub>BAT</sub> < V <sub>ORE</sub> V <sub>BUS</sub> > V <sub>SLP</sub> , R <sub>SENSE</sub>		550		1250	mA
	Charge Current Accuracy Across R <sub>SENSE</sub>	20mV ≤ V <sub>IREG</sub> ≤	FAN5400-02	95	100	105	
I <sub>OCHRG</sub>		40mV	FAN5403-05	92	97	102	%
		\/ > 40m\/	FAN5400-02	97	100	103	/0
		V <sub>IREG</sub> > 40mV	FAN5403-05	94	97	100	
Weak Batter	ry Detection						
	Weak Battery Threshold Range			3.4		3.7	V
$V_{LOWV}$	Weak Battery Threshold Accuracy			-5		+5	%
	Weak Battery Deglitch Time	Rising Voltage, 2m\	Overdrive		30		ms
Logic Levels	s: DISABLE, SDA, SCL, OTG						
V <sub>IH</sub>	High-Level Input Voltage			1.05			V
$V_{IL}$	Low-Level Input Voltage					0.4	V
I <sub>IN</sub>	Input Bias Current	Input Tied to GND o	r V <sub>IN</sub>		0.01	1.00	μΑ
Charge Tern	nination Detection						
	Termination Current Range	$V_{BAT} > V_{OREG} - V_{RCH}$ $R_{SENSE}$ =68m $\Omega$	$_{\rm I},V_{\rm BUS}>V_{\rm SLP},$	50		400	mA
I <sub>(TERM)</sub>	Tormination Current Assuran	[V <sub>CSIN</sub> – V <sub>BAT</sub> ] from 3	BmV to 20mV	-25		+25	0/
,	Termination Current Accuracy	[V <sub>CSIN</sub> – V <sub>BAT</sub> ] from 20mV to 40mV		-5		+5	%
	Termination Current Deglitch Time	2mV Overdrive			30		ms
1.8V Linear	Regulator	-				•	•
$V_{REG}$	1.8V Regulator Output	I <sub>REG</sub> from 0 to 2mA,	FAN5403-05	1.7	1.8	1.9	V

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## **Electrical Specifications**

Unless otherwise specified: according to the circuit of Figure 1; recommended operating temperature range for  $T_J$  and  $T_A$ ;  $V_{BUS}$ =5.0V;  $HZ_MODE$ ;  $OPA_MODE$ =0; (Charge Mode); SCL, SDA, OTG=0 or 1.8V; and typical values are for  $T_J$ =25°C.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
Input Power	Source Detection			•		•
V <sub>IN(MIN)1</sub>	VBUS Input Voltage Rising	To Initiate and Pass VBUS Validation		4.29	4.42	V
V <sub>IN(MIN)2</sub>	Minimum VBUS during Charge	During Charging		3.71	3.94	V
t <sub>VBUS_VALID</sub>	VBUS Validation Time			30		ms
Special Cha	rger (V <sub>BUS</sub> ) (FAN5403 – FAN5405)		•			•
V <sub>SP</sub>	Special Charger Setpoint Accuracy		-3		+3	%
Input Curren	nt Limit		•	1		
	land to Comment Line it There also also	I <sub>IN</sub> Set to 100mA	88	93	98	
I <sub>INLIM</sub>	Input Current Limit Threshold	I <sub>IN</sub> Set to 500mA	450	475	500	mA
V <sub>REF</sub> Bias Ge	enerator		•		·	
.,	Bias Regulator Voltage	$V_{BUS} > V_{IN(MIN)}$ or $V_{BAT} > V_{BAT(MIN)}$			6.5	V
$V_{REF}$	Short-Circuit Current Limit			20		mA
Battery Rech	harge Threshold		•			•
.,	Recharge Threshold	Below V <sub>(OREG)</sub>	100	120	150	mV
$V_{RCH}$	Deglitch Time	V <sub>BAT</sub> Falling Below V <sub>RCH</sub> Threshold		130		ms
STAT Outpu	t			1		
V <sub>STAT(OL)</sub>	STAT Output Low	I <sub>STAT</sub> =10mA			0.4	V
I <sub>STAT(OH)</sub>	STAT High Leakage Current	V <sub>STAT</sub> =5V			1	μΑ
Battery Dete	ection				l	
I <sub>DETECT</sub>	Battery Detection Current before Charge Done (Sink Current) <sup>(4)</sup>	Begins after Termination Detected		-0.80		mA
t <sub>DETECT</sub>	Battery Detection Time	and V <sub>BAT</sub> ≤ V <sub>OREG</sub> –V <sub>RCH</sub>		262		ms
Sleep Comp	arator			•		
$V_{SLP}$	Sleep-Mode Entry Threshold, V <sub>BUS</sub> – V <sub>BAT</sub>	$2.3V \le V_{BAT} \le V_{OREG}$ , $V_{BUS}$ Falling	0	0.04	0.10	V
V <sub>SLP_EXIT</sub>	Deglitch Time for VBUS Rising Above $V_{SLP} + V_{SLP\_EXIT}$	Rising Voltage		30		ms
Power Switc	thes (see Figure 3)					
	Q3 On Resistance (VBUS to PMID)	I <sub>IN(LIMIT)</sub> =500mA		180	250	
$R_{DS(ON)}$	Q1 On Resistance (PMID to SW)			130	225	mΩ
	Q2 On Resistance (SW to GND)			150	225	
Charger PW	M Modulator					
$f_{SW}$	Oscillator Frequency		2.7	3.0	3.3	MHz
D <sub>MAX</sub>	Maximum Duty Cycle				100	%
D <sub>MIN</sub>	Minimum Duty Cycle			0		%
I <sub>SYNC</sub>	Synchronous to Non-Synchronous Current Cut-Off Threshold <sup>(5)</sup>	Low-Side MOSFET (Q2) Cycle-by- Cycle Current Limit		140		mA

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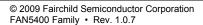
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Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
<b>Boost Mode</b>	Operation (OPA_MODE=1, HZ_MODE	DE=0)	•	•		•
M	Decet Outset Velters at VPLIC	2.5V < V <sub>BAT</sub> < 4.5V, I <sub>LOAD</sub> from 0 to 200mA	4.80	5.07	5.17	
$V_{BOOST}$	Boost Output Voltage at VBUS	2.7V < V <sub>BAT</sub> < 4.5V, I <sub>LOAD</sub> from 0 to 200mA	4.85	5.07	5.17	V
I <sub>BAT(BOOST)</sub>	Boost Mode Quiescent Current	PFM Mode, V <sub>BAT</sub> =3.6V, I <sub>OUT</sub> =0		140	300	μА
I <sub>LIMPK(BST)</sub>	Q2 Peak Current Limit		1100	1380	1660	mA
10/10	Minimum Battery Voltage for Boost	While Boost Active		2.42		.,
UVLO <sub>BST</sub>	Operation	To Start Boost Regulator		2.58	2.70	V
VBUS Load	Resistance					
Б.	VPLIC L. BOND B	Normal Operation		1500		ΚΩ
R <sub>VBUS</sub>	VBUS to PGND Resistance	Charger Validation		100		Ω
Protection a	nd Timers			•		•
VDLIO	VBUS Over-Voltage Shutdown	V <sub>BUS</sub> Rising	6.09	6.29	6.49	V
VBUS <sub>OVP</sub>	Hysteresis	V <sub>BUS</sub> Falling		100		mV
I <sub>LIMPK(CHG)</sub>	Q1 Cycle-by-Cycle Peak Current Limit	Charge Mode		2.3		Α
V	Battery Short-Circuit Threshold	V <sub>BAT</sub> Rising	1.95	2.00	2.05	V
$V_{SHORT}$	Hysteresis	V <sub>BAT</sub> Falling		100		V
I <sub>SHORT</sub>	Linear Charging Current	V <sub>BAT</sub> < V <sub>SHORT</sub>	20	30	40	mA
т	Thermal Shutdown Threshold <sup>(6)</sup>	T <sub>J</sub> Rising		145		°C
T <sub>SHUTDWN</sub>	Hysteresis <sup>(6)</sup>	T <sub>J</sub> Falling		10		
T <sub>CF</sub>	Thermal Regulation Threshold <sup>(6)</sup>	Charge Current Reduction Begins		120		°C
t <sub>INT</sub>	Detection Interval			2.1		s
4	32-Second Timer <sup>(7)</sup>	Charger Enabled	20.5	25.2	28.0	
t <sub>32S</sub>	32-Second Timer	Charger Disabled	18.0	25.2	34.0	S
t <sub>15MIN</sub>	15-Minute Timer	15-Minute Mode (FAN5400, FAN5402, FAN5404, FAN5405)	12.0	13.5	15.0	min
$\Delta t_{LF}$	Low-Frequency Timer Accuracy	Charger Inactive	-25		25	%

### Notes:

- 4. Negative current is current flowing from the battery to  $V_{\text{BUS}}$  (discharging the battery).
- 5. Q2 always turns on for 60ns, then turns off if current is below I<sub>SYNC</sub>.
- 6. Guaranteed by design; not tested in production.
- 7. This tolerance (%) applies to all timers on the IC, including soft-start and deglitching timers.



## I<sup>2</sup>C Timing Specifications

Guaranteed by design.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
		Standard Mode			100	
		Fast Mode			400	1
t <sub>SCL</sub>	SCL Clock Frequency	High-Speed Mode, C <sub>B</sub> ≤ 100pF			3400	kHz
		High-Speed Mode, C <sub>B</sub> ≤ 400pF			1700	<b>.</b>
	Bus-Free Time between STOP	Standard Mode		4.7	100 400 3400	
t <sub>BUF</sub>	and START Conditions	Fast Mode		1.3		μS
		Standard Mode		4		μS
t <sub>HD;STA</sub>	START or Repeated START Hold Time	Fast Mode		600		ns
	Hold Tille	High-Speed Mode		160		ns
		Standard Mode		4.7		μS
		Fast Mode		1.3		μS
$t_{LOW}$	SCL LOW Period	High-Speed Mode, C <sub>B</sub> ≤ 100pF		160		ns
thd;sta Since the second secon		High-Speed Mode, C <sub>B</sub> ≤ 400pF		320		ns
		Standard Mode		4		μS
		Fast Mode		600		ns
t <sub>HIGH</sub>	SCL HIGH Period	High-Speed Mode, C <sub>B</sub> ≤ 100pF		60		ns
		High-Speed Mode, C <sub>B</sub> ≤ 400pF		120		ns
		Standard Mode		4.7		μS
t <sub>SU:STA</sub>	Repeated START Setup Time	Fast Mode		600		ns
00,0111		High-Speed Mode		160		ns
		Standard Mode		250		
t <sub>SU:DAT</sub>	Data Setup Time	Fast Mode		100		ns
5 5,2		High-Speed Mode		10		<b>≜,</b>
		Standard Mode	0		3.45	μS
		Fast Mode	0		900	ns
t <sub>HD;DAT</sub>	Data Hold Time	High-Speed Mode, C <sub>B</sub> ≤ 100pF	0		20	ns
		High-Speed Mode, C <sub>B</sub> < 400pF	0		150	ns
		Standard Mode	20+0	).1C <sub>B</sub>	1000	
		Fast Mode		).1C <sub>B</sub>		<u>.</u>
t <sub>RCL</sub>	SCL Rise Time	High-Speed Mode, C <sub>B</sub> ≤ 100pF		10	80	ns
		High-Speed Mode, C <sub>B</sub> ≤ 400pF		20	160	
		Standard Mode	20+0	).1C <sub>B</sub>		
		Fast Mode	20+0	).1C <sub>B</sub>	300	
$t_{FCL}$	SCL Fall Time	High-Speed Mode, C <sub>B</sub> ≤ 100pF		10		ns
		High-Speed Mode, C <sub>B</sub> ≤ 400pF		20		1
		Standard Mode	20+0	).1C <sub>B</sub>	1	
t <sub>RDA</sub>	SDA Rise Time Rise Time of SCL after a	Fast Mode		).1C <sub>B</sub>		1
t <sub>RCL1</sub>	Repeated START Condition	High-Speed Mode, C <sub>B</sub> ≤ 100pF		10		ns
	and after ACK Bit	High-Speed Mode, C <sub>B</sub> ≤ 400pF		20	160	†

Continued on the following page...

## I<sup>2</sup>C Timing Specifications

Guaranteed by design.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
		Standard Mode	20+0	).1C <sub>B</sub>	300	
<b>+</b>	SDA Fall Time	Fast Mode	20+0	).1C <sub>B</sub>	300	1
t <sub>FDA</sub>	SDA Fall Time	High-Speed Mode, C <sub>B</sub> ≤ 100pF		10	80	ns
		High-Speed Mode, $C_B \le 400 pF$		20	160	
		Standard Mode		4		μS
t <sub>su;sto</sub>	Stop Condition Setup Time	Fast Mode		600		ns
		High-Speed Mode		160		ns
Св	Capacitive Load for SDA, SCL				400	pF

## **Timing Diagrams**

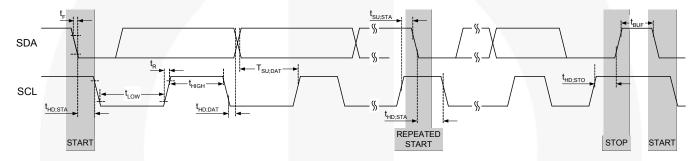


Figure 5. I<sup>2</sup>C Interface Timing for Fast and Slow Modes

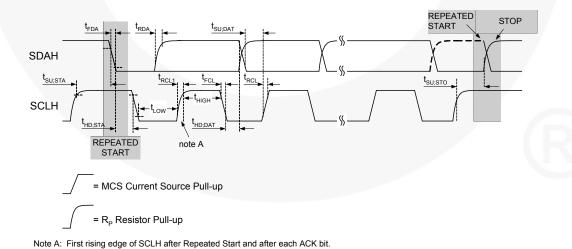
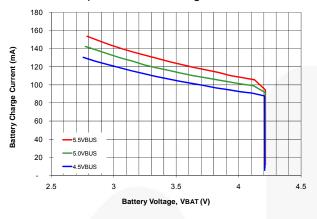


Figure 6. I<sup>2</sup>C Interface Timing for High-Speed Mode

## **Charge Mode Typical Characteristics**

Unless otherwise specified, circuit of Figure 1, V<sub>OREG</sub>=4.2V, V<sub>BUS</sub>=5.0V, and T<sub>A</sub>=25°C.



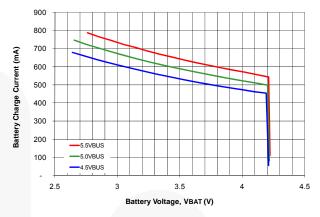
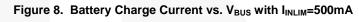
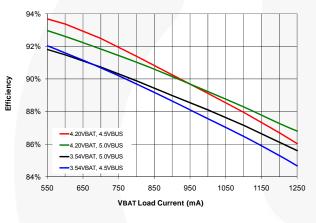


Figure 7. Battery Charge Current vs.  $V_{\text{BUS}}$  with  $I_{\text{INLIM}} = 100 \text{mA}$ 





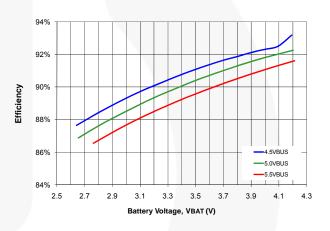
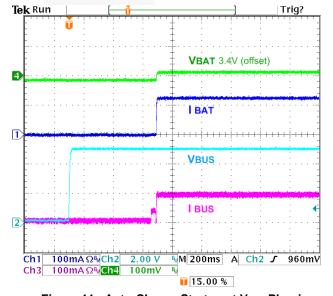


Figure 9. Charger Efficiency, No I<sub>INLIM</sub>, I<sub>OCHARGE</sub>=1,250mA

Figure 10. Charger Efficiency vs. V<sub>BUS</sub>, I<sub>INLIM</sub>=500mA



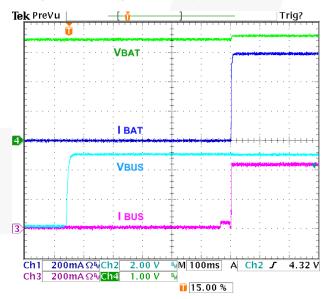
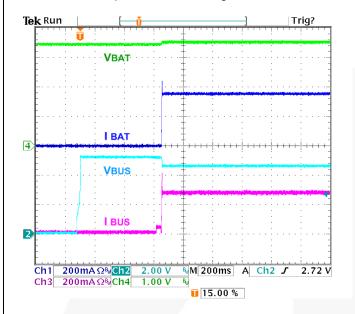


Figure 11. Auto-Charge Startup at  $V_{BUS}$  Plug-in,  $I_{INLIM}$ =100mA, OTG=1,  $V_{BAT}$ =3.4V

Figure 12. Auto-Charge Startup at  $V_{BUS}$  Plug-in,  $I_{INLIM}$ =500mA, OTG=1,  $V_{BAT}$ =3.4V

## **Charge Mode Typical Characteristics**

Unless otherwise specified, circuit of Figure 1, V<sub>OREG</sub>=4.2V, V<sub>BUS</sub>=5.0V, and T<sub>A</sub>=25°C.

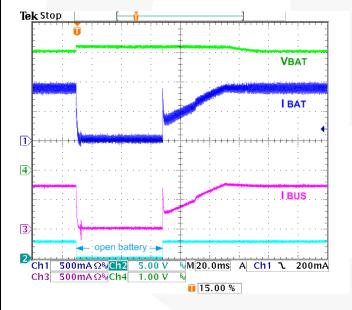


Tek Stop VBAT

| IBAT | IBUS | IBUS

Figure 13. AutoCharge Startup with 300mA Limited Charger / Adaptor, I<sub>INLIM</sub>=500mA, OTG=1, V<sub>BAT</sub>=3.4V

Figure 14. Charger Startup with HZ\_MODE Bit Reset, I<sub>INLIM</sub>=500mA, I<sub>OCHARGE</sub>=950mA, OREG=4.2V, V<sub>BAT</sub>=3.6V



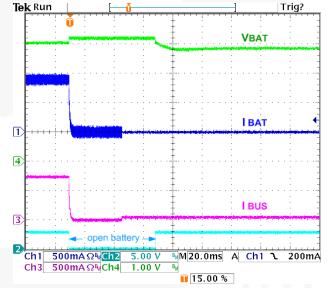


Figure 15. Battery Removal / Insertion during Charging,  $V_{BAT}$ =3.9V,  $I_{OCHARGE}$ =950mA, No  $I_{INLIM}$ , TE=0

Figure 16. Battery Removal / Insertion during Charging, V<sub>BAT</sub>=3.9V, I<sub>OCHARGE</sub>=950mA, No I<sub>INLIM</sub>, TE=1

## **Charge Mode Typical Characteristics**

Unless otherwise specified, circuit of Figure 1, V<sub>OREG</sub>=4.2V, V<sub>BUS</sub>=5.0V, and T<sub>A</sub>=25°C.

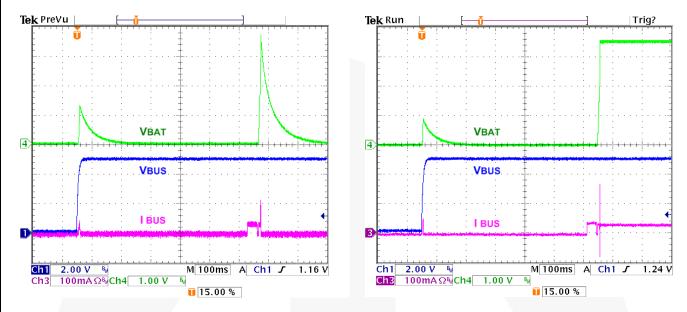
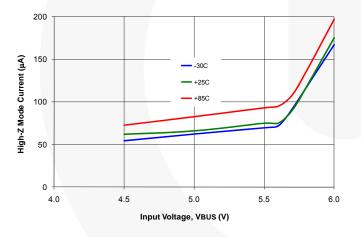


Figure 17. No Battery at V<sub>BUS</sub> Power-up; FAN5400, FAN5403 Figure 18. No Battery at V<sub>BUS</sub> Power-up; FAN5402, FAN5405



1.82

1.81

1.80

1.79

--10C, 5.0VBUS

1.78

--+25C, 5.0VBUS

--+85C, 5.0VBUS

1.77

0 1 2 3 4 5

1.8V Regulator Load Current (mA)

Figure 19. VBUS Current in High-Impedance Mode with Battery Open

Figure 20. V<sub>REG</sub> 1.8V Output Regulation

#### **Boost Mode Typical Characteristics** Unless otherwise specified, using circuit of Figure 1, VBAT=3.6V, TA=25°C. 100 100 95 95 90 Efficiency (%) Efficiency (%) 85 85 -10C, 3.6VBAT 80 80 - 3.6VBAT +25C, 3.6VBAT 4 2VRAT +85C, 3.6VBAT 75 75 50 50 100 150 200 300 0 100 150 200 300 0 250 250 VBUS Load Current (mA) VBUS Load Current (mA) Figure 21. Efficiency vs. VBAT Figure 22. Efficiency Over Temperature 5.12 5.12 2.7VBAT -10C. 3.6VBAT 5.09 5.09 3.6VBAT +25C, 3.6VBAT 4.2VBAT 5.06 5.06 VBUS (V) 5.03 5.03 5.00 5.00 4.97 4.97 4.94 50 100 300 0 50 100 150 200 250 300 0 150 200 250 VBUS Load Current (mA) VBUS Load Current (mA) Figure 23. Output Regulation vs. VBAT Figure 24. Output Regulation Over Temperature 250 20 +25C 200 15 High-Z Mode Current (µA) +85C Quiescent Current (µA) 150 10 100 -30C +85C 50 0 2.5 2.5 3.5 2 3.5 4.5

Battery Voltage, VBAT (V)

Figure 25. Quiescent Current

Battery Voltage, VBAT (V)

Figure 26. High-Impedance Mode Battery Current

## **Boost Mode Typical Characteristics**

Unless otherwise specified, using circuit of Figure 1, V<sub>BAT</sub>=3.6V, T<sub>A</sub>=25°C.

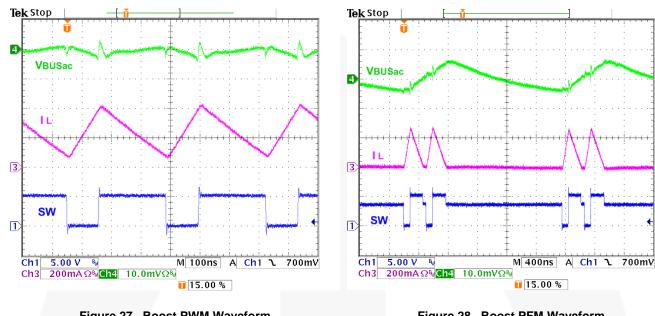


Figure 27. Boost PWM Waveform

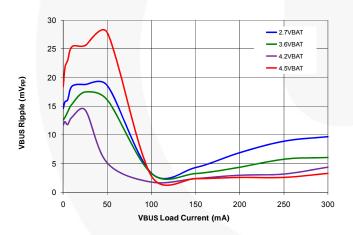


Figure 29. Output Ripple vs. VBAT

Figure 28. Boost PFM Waveform

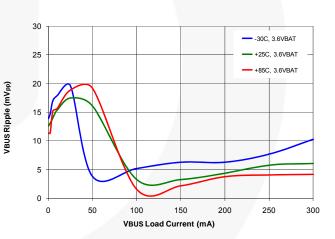


Figure 30. Output Ripple vs. Temperature

## **Boost Mode Typical Characteristics**

Unless otherwise specified, using circuit of Figure 1, V<sub>BAT</sub>=3.6V, T<sub>A</sub>=25°C.

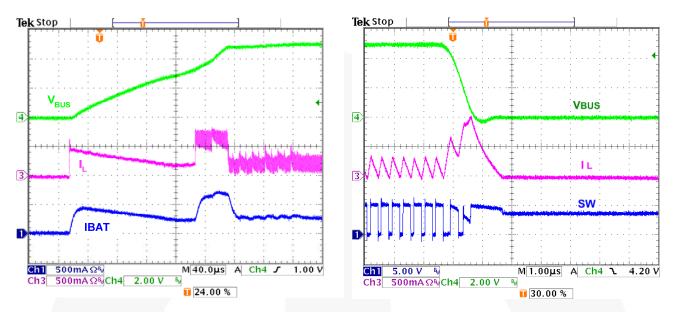


Figure 31. Startup, 3.6V<sub>BAT</sub>, 44 $\Omega$  Load, Additional 10 $\mu$ F, X5R Across V<sub>BUS</sub>

Figure 32.  $V_{BUS}$  Fault Response, 3.6 $V_{BAT}$ 

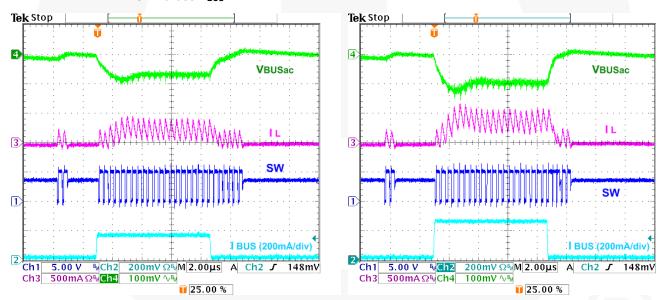


Figure 33. Load Transient, 5-155-5mA, t<sub>R</sub>=t<sub>F</sub>=100ns

Figure 34. Load Transient, 5-255-5mA, t<sub>R</sub>=t<sub>F</sub>=100ns

## **Circuit Description / Overview**

When charging batteries with a current-limited input source, such as USB, a switching charger's high efficiency over a wide range of output voltages minimizes charging time.

FAN540X combines a highly integrated synchronous buck regulator for charging with a synchronous boost regulator, which can supply 5V to USB On-The-Go (OTG) peripherals. The regulator employs synchronous rectification for both the charger and boost regulators to maintain high efficiency over a wide range of battery voltages and charge states.

The FAN540X has three operating modes:

- Charge Mode: Charges a single-cell Li-ion or Li-polymer battery.
- Boost Mode: Provides 5V power to USB-OTG with an integrated synchronous rectification boost regulator using the battery as input.
- High-Impedance Mode:
   Both the boost and charging circuits are OFF in this mode. Current flow from VBUS to the battery or from the battery to VBUS is blocked in this mode. This mode consumes very little current from VBUS or the battery.

Note: Default settings are denoted by **bold typeface**.

## **Charge Mode**

In Charge Mode, FAN540X employs four regulation loops:

- Input Current: Limits the amount of current drawn from VBUS. This current is sensed internally and can be programmed through the I<sup>2</sup>C interface.
- 2. Charging Current: Limits the maximum charging current. This current is sensed using an external R<sub>SENSE</sub> resistor.
- 3. Charge Voltage: The regulator is restricted from exceeding this voltage. As the internal battery voltage rises, the battery's internal impedance and R<sub>SENSE</sub> work in conjunction with the charge voltage regulation to decrease the amount of current flowing to the battery. Battery charging is completed when the voltage across R<sub>SENSE</sub> drops below the I<sub>TERM</sub> threshold.
- Temperature: If the IC's junction temperature reaches 120°C, charge current is continuously reduced until the IC's temperature stabilizes at 120°C.

In addition, the FAN5403-05 employ an additional loop to limit the amount of drop on VBUS to a programmable voltage ( $V_{SP}$ ) to accommodate "special chargers" that limit current to a lower current than might be available from a "normal" USB wall charger.

### **Battery Charging Curve**

If the battery voltage is below  $V_{SHORT}$ , a linear current source pre-charges the battery until  $V_{BAT}$  reaches  $V_{SHORT}$ . The PWM charging circuit is then started and the battery is charged

with a constant current if sufficient input power is available. The current slew rate is limited to prevent overshoot.

The FAN540X is designed to work with a current-limited input source at VBUS. During the current regulation phase of charging,  $I_{\text{INLIM}}$  or the programmed charging current limits the amount of current available to charge the battery and power the system. The effect of  $I_{\text{INLIM}}$  on  $I_{\text{CHARGE}}$  can be seen in Figure 36.

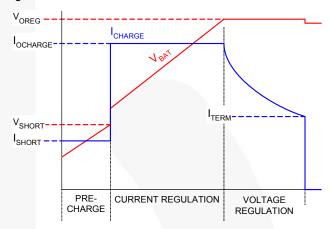


Figure 35. Charge Curve, I<sub>CHARGE</sub> Not Limited by I<sub>INLIM</sub>

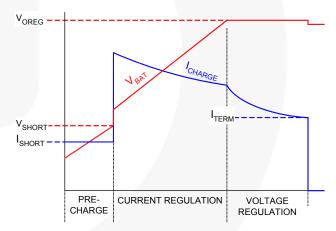


Figure 36. Charge Curve, I<sub>INLIM</sub> Limits I<sub>CHARGE</sub>

Assuming that  $V_{OREG}$  is programmed to the cell's fully charged "float" voltage, the current that the battery accepts with the PWM regulator limiting its output (sensed at VBAT) to  $V_{OREG}$  declines, and the charger enters the voltage regulation phase of charging. When the current declines to the programmed  $I_{TERM}$  value, the charge cycle is complete. Charge current termination can be disabled by resetting the TE bit (REG1[3]).

The charger output or "float" voltage can be programmed by the OREG bits from 3.5V to 4.44V in 20mV increments, as shown in Table 3.

Table 3. OREG Bits (OREG[7:2]) vs. Charger  $V_{OUT}$  ( $V_{OREG}$ ) Float Voltage

00 01 <b>02</b> 03	3.50 3.52
01 <b>02</b>	3.52
02	
	0.54
03	3.54
00	3.56
04	3.58
05	3.60
06	3.62
07	3.64
80	3.66
09	3.68
0A	3.70
0B	3.72
0C	3.74
D0	3.76
0E	3.78
0F	3.80
10	3.82
11	3.84
12	3.86
13	3.88
14	3.90
15	3.92
16	3.94
17	3.96
18	3.98
19	4.00
1A	4.02
1B	4.04
1C	4.06
1D	4.08
1E	4.10
	06 07 08 09 0A 0B 0C 0D 0E 10 11 12 13 14 15 16 17 18 19 1A 1B 1C 1D

Hex	VOREG
20	4.14
21	4.16
22	4.18
23	4.20
24	4.22
25	4.24
26	4.26
27	4.28
28	4.30
29	4.32
2A	4.34
2B	4.36
2C	4.38
2D	4.40
2E	4.42
2F	4.44
30	4.44
31	4.44
32	4.44
33	4.44
34	4.44
35	4.44
36	4.44
37	4.44
38	4.44
39	4.44
3A	4.44
3B	4.44
3C	4.44
3D	4.44
3E	4.44
	20 21 22 23 24 25 26 27 28 29 2A 2B 2C 2D 2E 2F 30 31 32 33 34 35 36 37 38 39 3A 3B 3C 3D

The following charging parameters can be programmed by the host through  $I^2C$ :

**Table 4. Programmable Charging Parameters** 

Parameter	Name	Register
Output Voltage Regulation	V <sub>OREG</sub>	REG2[7:2]
Battery Charging Current Limit	I <sub>OCHRG</sub>	REG4[6:4]
Input Current Limit	I <sub>INLIM</sub>	REG1[7:6]
Charge Termination Limit	I <sub>TERM</sub>	REG4[2:0]
Weak Battery Voltage	$V_{LOWV}$	REG1[5:4]

A new charge cycle begins when one of the following occurs:

- The battery voltage falls below V<sub>OREG</sub> V<sub>RCH</sub>
- VBUS Power On Reset (POR) clears and the battery voltage is below the weak battery threshold (V<sub>LOWV</sub>).
   This occurs for all versions except the FAN5401.
- CE or HZ\_MODE is reset through I<sup>2</sup>C write to CONTROL1 (R1) register.

### Charge Current Limit (IOCHARGE)

Table 5. I<sub>OCHARGE</sub> (REG4 [6:4]) Current as Function of I<sub>OCHARGE</sub> Bits and R<sub>SENSE</sub> Resistor Values

DEC	BIN	HEX	V <sub>RSENSE</sub>	I <sub>OCHARG</sub>	<sub>sE</sub> (mA)
DEC	DIN	ПЕХ	(mV)	68mΩ	100mΩ
0	000	00	37.4	550	374
1	001	01	44.2	650	442
2	010	02	51.0	750	510
3	011	03	57.8	850	578
4	100	04	64.6	950	646
5	101	05	71.4	1050	714
6	110	06	78.2	1150	782
7	111	07	85.0	1250	850

### **Termination Current Limit**

Current charge termination is enabled when TE (REG1[3])=1. Typical termination current values are given in Table 6.

Table 6.  $I_{TERM}$  Current as Function of  $I_{TERM}$  Bits (REG4[2:0]) and  $R_{SENSE}$  Resistor Values

	FAN5400 - FAN5402			FAN540	03 - FA	N5405
				V <sub>RSENSE</sub>	I <sub>TERM</sub> (mA)	
ITERM		(mV) 68mΩ 100mΩ	(m\/)	(mV) $68m\Omega$ $100m\Omega$ (mV)	68mΩ	100mΩ
0	3.4	50	34	3.3	49	33
1	6.8	100	68	6.6	97	66
2	10.2	150	102	9.9	146	99
3	13.6	200	136	13.2	194	132
4	17.0	250	170	16.5	243	165
5	20.4	300	204	19.8	291	198
6	23.8	350	238	23.1	340	231
7	27.2	400	272	26.4	388	264

When the charge current falls below  $I_{TERM}$ , PWM charging stops and the STAT bits change to READY (00) for about 500ms while the IC determines whether the battery and charging source are still connected. STAT then changes to CHARGE DONE (10), provided the battery and charger are still connected.

### **PWM Controller in Charge Mode**

The IC uses a current-mode PWM controller to regulate the output voltage and battery charge currents. The synchronous rectifier (Q2) has a negative current limit that turns off Q2 at 140mA to prevent current flow from the battery.

## **Safety Timer**

This section references Figure 41 and Figure 42.

At the beginning of charging, the IC starts a 15-minute timer ( $t_{15\text{MIN}}$ ). When this timer times out, charging is terminated. Writing to any register through I<sup>2</sup>C stops and resets the  $t_{15\text{MIN}}$  timer, which in turn starts a 32-second timer ( $t_{32\text{S}}$ ). Setting the TMR\_RST bit (REG0[7]) resets the  $t_{32\text{S}}$  timer. If the  $t_{32\text{S}}$  timer times out, charging is terminated, the registers are set to their default values, and charging resumes using the default values with the  $t_{15\text{MIN}}$  timer running.

Normal charging is controlled by the host with the  $t_{328}$  timer running to ensure that the host is alive. Charging with the  $t_{15\text{MIN}}$  timer running is used for charging that is unattended by the host. If the  $t_{15\text{MIN}}$  timer expires, the IC turns off the charger, sets the  $\overline{\text{CE}}$  bit, and indicates a timer fault (110) on the FAULT bits (REG0[2:0]). This sequence prevents overcharge if the host fails to reset the  $t_{328}$  timer.

## V<sub>BUS</sub> POR / Non-Compliant Charger Rejection

When the IC detects that  $V_{BUS}$  has risen above  $V_{IN(MIN)1}$  (4.4V), the IC applies a 110 $\Omega$  load from VBUS to GND. To clear the VBUS POR (Power-On-Reset) and begin charging, VBUS must remain above  $V_{IN(MIN)1}$  and below VBUS<sub>OVP</sub> for  $t_{VBUS\_VALID}$  (30ms) before the IC initiates charging. The VBUS validation sequence always occurs before charging is initiated or re-initiated (for example, after a VBUS OVP fault or a  $V_{RCH}$  recharge initiation).

 $t_{\text{VBUS\_VALID}}$  ensures that unfiltered 50/60hz chargers and other non-compliant chargers are rejected.

### **USB-Friendly Boot Sequence**

For all versions except FAN5401, FAN5404

At VBUS POR, when the battery voltage is above the weak battery threshold (V<sub>LOWV</sub>), the IC operates in accordance with its  $I^2C$  register settings. If  $V_{BAT} < V_{LOWV}$ , the IC sets all registers to their default values and enables the charger using an input current limit controlled by the OTG pin (100mA if OTG is LOW and 500mA if OTG is HIGH). This feature can revive a battery whose voltage is too low to ensure reliable host operation. Charging continues in the absence of host communication even after the battery has reached V<sub>OREG</sub>, whose default value is 3.54V, and the charger remains active until t<sub>15MIN</sub> times out. Once the host processor begins writing to the IC, charging parameters are set by the host, which must continually reset the t<sub>328</sub> timer to continue charging using the programmed charging parameters. If t<sub>32S</sub> times out, the register defaults are loaded, the FAULT bits are set to 110, STAT is pulsed HIGH, and charging continues with default charge parameters.

The FAN5401 and FAN5404 do not automatically initiate charging at VBUS POR. Instead, they wait for the host to initiate charging through I<sup>2</sup>C commands.

### **Input Current Limiting**

To minimize charging time without overloading VBUS current limitations, the IC's input current limit can be programmed by the  $I_{INLIM}$  bits (REG1[7:6]).

**Table 7. Input Current Limit** 

I <sub>INLIM</sub> REG1[7:6]	Input Current Limit
00	100mA
01	500mA
10	800mA
11	No limit

For all versions except the FAN5401 and FAN5404, the OTG pin establishes the input current limit when  $t_{15\text{MIN}}$  is running. For the FAN5401 and FAN5404, no charging occurs automatically at VBUS POR, so the input current limit is established by the  $I_{\text{INLIM}}$  bits.

## **Flow Charts**

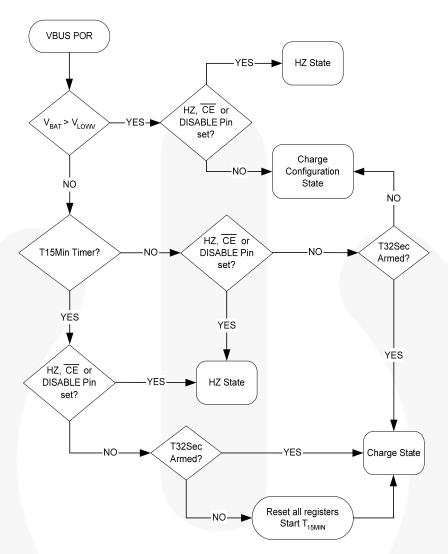
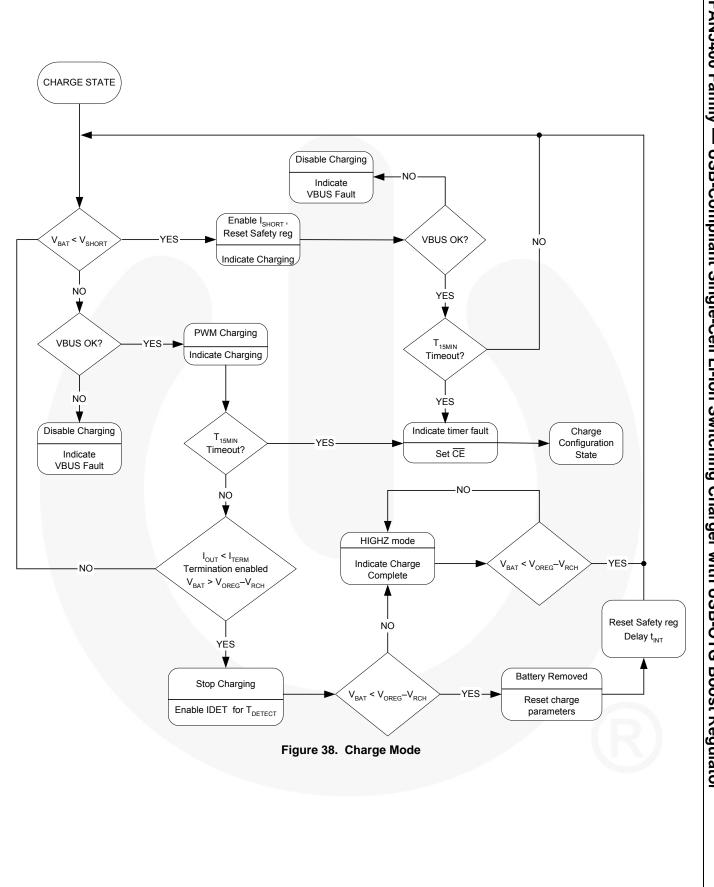


Figure 37. Charger VBUS POR



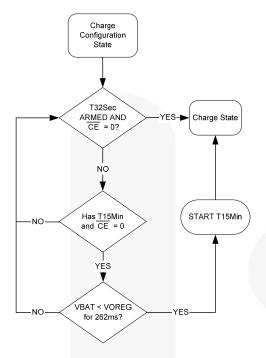


Figure 39. Charge Configuration

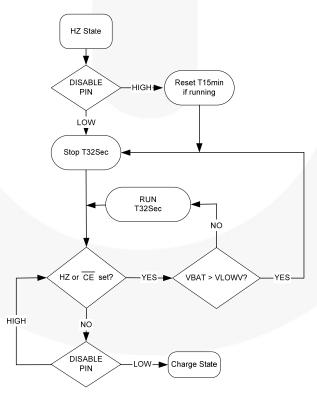


Figure 40. HZ-State

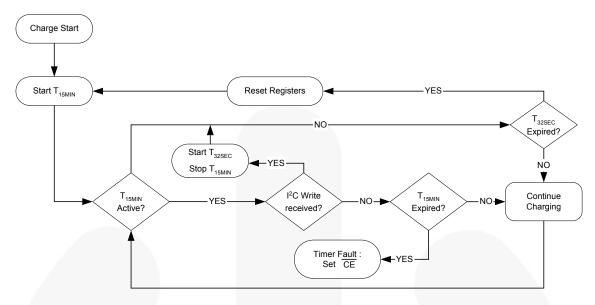


Figure 41. Timer Flow Chart for FAN5400, FAN5402, FAN5403, FAN5405

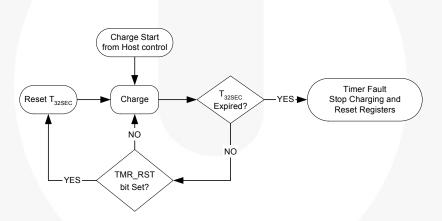


Figure 42. Timer Flow Chart for FAN5401, FAN5404

## **Special Charger**

FAN5403-05 Only

The FAN5403, FAN5404, and FAN5405 have additional functionality to limit input current in case a current-limited "special charger" is supplying VBUS. The FAN5403-05 slowly increases the charging current until either:

I<sub>INLIM</sub> or I<sub>OCHARGE</sub> is reached

or

V<sub>BUS</sub>=V<sub>SP</sub>.

If  $V_{BUS}$  collapses to  $V_{SP}$  when the current is ramping up, the FAN5403-05 charge with an input current that keeps  $V_{BUS}$ = $V_{SP}$ . When the  $V_{SP}$  control loop is limiting the charge current, the SP bit (REG5[4]) is set.

Table 8. V<sub>SP</sub> as Function of SP Bits (REG5[2:0])

S			
DEC	BIN	HEX	V <sub>SP</sub>
0	000	00	4.213
1	001	01	4.293
2	010	02	4.373
3	011	03	4.453
4	100	04	4.533
5	101	05	4.613
6	110	06	4.693
7	111	07	4.773

### **Safety Settings**

FAN5403-FAN5405 Only

The FAN5403-05 contain a SAFETY register (REG6) that prevents the values in OREG (REG2[7:2]) and IOCHARGE (REG4[6:4]) from exceeding the values of the VSAFE and ISAFE values.

After  $V_{BAT}$  exceeds  $V_{SHORT}$ , the SAFETY register is loaded with its default value and may be written only before any other register is written. After writing to any other register, the SAFETY register is locked until  $V_{BAT}$  falls below  $V_{SHORT}$ .

The ISAFE (REG6[6:4]) and VSAFE (REG6[3:0]) registers establish values that limit the maximum values of  $I_{\rm OCHARGE}$  and  $V_{\rm OREG}$  used by the control logic. If the host attempts to write a value higher than VSAFE or ISAFE to OREG or IOCHARGE, respectively; the VSAFE, ISAFE value appears as the OREG, IOCHARGE register value, respectively.

Table 9. I<sub>SAFE</sub> (I<sub>OCHARGE</sub> Limit) as Function of ISAFE Bits (REG6[6:4])

ISAFE	ISAFE (REG6[6:4])				
DEC	BIN	HEX	V <sub>RSENSE</sub> (mV)	I <sub>SAFE</sub>	(mA)
DEC				68mΩ	100mΩ
0	000	00	37.4	550	374
1	001	01	44.2	650	442
2	010	02	51.0	750	510
3	011	03	57.8	850	578
4	100	04	64.6	950	646
5	101	05	71.4	1050	714
6	110	06	78.2	1150	782
7	111	07	85.0	1250	850

Table 10.  $V_{SAFE}$  ( $V_{OREG}$  Limit) as Function of VSAFE Bits (REG6[3:0])

VSAF	VSAFE (REG6[3:0])			
DEC	BIN	HEX	Max. OREG (REG2[7:2])	VOREG Max.
0	0000	00	100011	4.20
1	0001	00	100100	4.22
2	0010	01	100101	4.24
3	0011	02	100110	4.26
4	0100	03	100111	4.28
5	0101	04	101000	4.30
6	0110	05	101001	4.32
7	0111	06	101010	4.34
8	1000	07	101011	4.36
9	1001	08	101100	4.38
10	1010	09	101101	4.40
11	1011	0A	101110	4.42
12	1100	0B	101111	4.44
13	1101	0C	110000	4.44
14	1110	0D	110001	4.44
15	1111	0E	110010	4.44

## Thermal Regulation and Protection

When the IC's junction temperature reaches  $T_{CF}$  (about 120°C), the charger reduces its output current to 550mA to prevent overheating. If the temperature increases beyond  $T_{SHUTDOWN}$ ; charging is suspended, the FAULT bits are set to 101, and STAT is pulsed HIGH. In Suspend Mode, all timers stop and the state of the IC's logic is preserved. Charging resumes at programmed current after the die cools to about 120°C.

Additional  $\theta_{JA}$  data points, measured using the FAN540X evaluation board, are given in Table 11 (measured with  $T_A \! = \! 25^{\circ} C).$  Note that as power dissipation increases, the effective  $\theta_{JA}$  decreases due to the larger difference between the die temperature and its ambient.

Table 11. FAN5400 Evaluation Board Measured  $\theta_{\text{JA}}$ 

Power (W)	θ <sub>JA</sub>
0.504	54°C/W
0.844	50°C/W
1.506	46°C/W

### **Charge Mode Input Supply Protection**

### Sleep Mode

When  $V_{BUS}$  falls below  $V_{BAT}$  +  $V_{SLP}$ , and  $V_{BUS}$  is above  $V_{IN(MIN)}$ , the IC enters Sleep Mode to prevent the battery from draining into VBUS. During Sleep Mode, reverse current is disabled by body switching Q1.

### Input Supply Low-Voltage Detection

The IC continuously monitors VBUS during charging. If  $V_{BUS}$  falls below  $V_{IN(MIN)}$ , the IC:

- 1. Terminates charging
- 2. Pulses the STAT pin, sets the STAT bits to 11, and sets the FAULT bits to 011.

If  $V_{\text{BUS}}$  recovers above the  $V_{\text{IN(MIN)}}$  rising threshold after time  $t_{\text{INT}}$  (about two seconds), the charging process is repeated. This function prevents the USB power bus from collapsing or oscillating when the IC is connected to a suspended USB port or a low-current-capable OTG device.

#### Input Over-Voltage Detection

When the V<sub>BUS</sub> exceeds VBUS<sub>OVP</sub>, the IC:

- 1. Turns off Q3
- 2. Suspends charging
- 3. Sets the FAULT bits to 001, sets the STAT bits to 11, and pulses the STAT pin.

When  $V_{BUS}$  falls about 150mV below VBUS<sub>OVP</sub>, the fault is cleared and charging resumes after  $V_{BUS}$  is revalidated (see VBUS POR / Non-Compliant Charger Rejection).

#### **VBUS Short While Charging**

If VBUS is shorted with a very low impedance while the IC is charging with  $I_{\text{INLIMIT}}{=}100\text{mA},$  the IC may not meet datasheet specifications until power is removed. To trigger this condition,  $V_{\text{BUS}}$  must be driven from 5V to GND with a high slew rate. Achieving this slew rate requires a  $0\Omega$  short to the USB cable less than 10cm from the connector.

### **Charge Mode Battery Detection & Protection**

### **VBAT Over-Voltage Protection**

The OREG voltage regulation loop prevents  $V_{BAT}$  from overshooting the OREG voltage by more than 50mV when the battery is removed. When the PWM charger runs with no battery, the TE bit is not set and a battery is inserted that is charged to a voltage higher than  $V_{OREG}$ ; PWM pulses stop. If no further pulses occur for 30ms, the IC sets the FAULT bits to 100, sets the STAT bits to 11, and pulses the STAT pin.

#### **Battery Detection During Charging**

The IC can detect the presence, absence, or removal of a battery if the termination bit (TE) is set. During normal charging, once  $V_{BAT}$  is close to  $V_{OREG}$  and the termination charge current is detected, the IC terminates charging and sets the STAT bits to 10. It then turns on a discharge current,  $I_{DETECT}$ , for  $I_{DETECT}$ . If  $I_{DETECT}$  is still above  $I_{OREG}$  and  $I_{OREG}$  is present and the IC sets the FAULT bits to 000. If  $I_{DETECT}$  below  $I_{OREG}$  is absent and the IC:

- Sets the registers to their default values.
- 2. Sets the FAULT bits to 111.
- Resumes charging with default values after t<sub>INT</sub>.

#### **Battery Short-Circuit Protection**

If the battery voltage is below the short-circuit threshold ( $V_{SHORT}$ ); a linear current source,  $I_{SHORT}$ , supplies  $V_{BAT}$  until  $V_{BAT} > V_{SHORT}$ .

#### **Battery Detection During Power-up**

For FAN5400 and FAN5403

At VBUS POR, a 5K $\Omega$  load is applied to VBAT for 500ms to discharge any residual system capacitance in case the battery is absent. If V<sub>BAT</sub> < V<sub>SHORT</sub>, linear charging commences. When V<sub>BAT</sub> rises above V<sub>SHORT</sub>, PWM charging proceeds with the float voltage (OREG) temporarily set to 4V. If the battery voltage exceeds 3.7V within 32ms of the beginning of PWM charging, the battery is absent. If battery absent is detected:

- 1. High-Impedance Mode is entered.
- 2. FAULT bits are set to 111.
- 3. The t<sub>15MIN</sub> timer is disabled until VBUS is removed.

If  $V_{\text{BAT}}$  remains below 3.7V during the initial 32ms period, the float voltage returns to the OREG register setting and PWM charging continues.

### System Operation with No Battery

The FAN5402 and FAN5405 continue charging after VBUS POR with the default parameters, regulating the  $V_{BAT}$  line to 3.54V until the host processor issues commands or the 15-minute timer expires. In this way, the FAN5402 and FAN5405 can start the system without a battery.

The FAN540X soft-start function can interfere with the system supply with battery absent. The soft-start activates whenever  $V_{\rm OREG}$ ,  $I_{\rm INLIM}$ , or  $I_{\rm OCHARGE}$  are set from a lower to higher value. During soft-start, the  $I_{\rm IN}$  limit drops to 100mA for about 1ms unless  $I_{\rm INLIM}$  is set to 11 (no limit). This could cause the system processor to fail to start. To avoid this behavior, use the following sequence.

- Set the OTG pin HIGH. When VBUS is plugged in, I<sub>INLIM</sub> is set to 500mA until the system processor powers up and can set parameters through I<sup>2</sup>C.
- 2. Program the Safety Register.
- 3. Set I<sub>INLIM</sub> to 11 (no limit).
- 4. Set OREG to the desired value (typically 4.18).
- 5. Reset the IOLEVEL bit, then set IOCHARGE.
- 6. Set I<sub>INLIM</sub> to 500mA if a USB source is connected.

During the initial system startup, while the charger IC is being programmed, the system current is limited to 325mA for 1ms during steps 4 and 5. This is the value of the soft-start  $I_{\text{CHARGE}}$  current used when  $I_{\text{INLIM}}$  is set to No Limit.

If the system is powered up without a battery present, the CV bit should be set. When a battery is inserted, the CV bit is cleared.

#### Charger Status / Fault Status

The STAT pin indicates the operating condition of the IC and provides a fault indicator for interrupt driven systems.

**Table 12. STAT Pin Function** 

EN_STAT	Charge State	STAT Pin
0	X	OPEN
Х	Normal Conditions	OPEN
1	Charging	LOW
Х	Fault (Charging or Boost)	128µs Pulse, then OPEN

The FAULT bits (R0[2:0]) indicate the type of fault in Charge Mode (see Table 13).

Table 13. Fault Status Bits During Charge Mode

F	Fault Bit		Fault Bit		Fault Description
B2	B1	В0	Fault Description		
0	0	0	Normal (No Fault)		
0	0	1	VBUS OVP		
0	1	0	Sleep Mode		
0	1	1	Poor Input Source		
1	0	0	Battery OVP		
1	0	1	Thermal Shutdown		
1	1	0	Timer Fault		
1	1	1	No Battery		

### **Charge Mode Control Bits**

Setting either HZ\_MODE or CE through I $^2$ C disables the charger and puts the IC into High-Impedance Mode and resets  $t_{32S}$ . If  $V_{BAT} < V_{LOWV}$  while in High-Impedance Mode,  $t_{32S}$  begins running and, when it overflows, all registers (except SAFETY) reset, which enables  $t_{15MIN}$  charging on versions with the 15-minute timer.

When  $t_{15MIN}$  overflows, the IC sets the CE bit and the IC enters High-Impedance Mode. If  $\overline{\text{CE}}$  was set by  $t_{15MIN}$  overflow, a new charge cycle can only be initiated through I<sup>2</sup>C or VBUS POR.

Setting the RESET bit clears all registers. If  $HZ\_MODE$  or  $\overline{CE}$  bits were set when the RESET bit is set, these bits are also cleared, but the  $t_{32S}$  timer is not started, and the IC remains in High-Impedance Mode.

Table 14. FAN5403–FAN5405 DISABLE Pin and CE Bit Functionality

Charging	Charging DISABLE Pin CE			
ENABLE	0	0	0	
DISABLE	X	1	X	
DISABLE	X	Х	1	
DISABLE	1	Х	X	

Raising the DISABLE pin stops  $t_{32S}$  from advancing, but does not reset it. If the DISABLE pin is raised during  $t_{15\text{MIN}}$  charging, the  $t_{15\text{MIN}}$  timer is reset.

#### **Operational Mode Control**

OPA\_MODE (REG1[0]) and the HZ\_MODE (REG1[1]) bits in conjunction with the FAULT state define the operational mode of the charger.

**Table 15. Operation Mode Control** 

HZ_MODE	OPA_MODE	FAULT	Operation Mode
0	0	0	Charge
0	X	1	Charge Configure
0	0 1		Boost
1	Х	Х	High Impedance

The IC resets the OPA\_MODE bit whenever the boost is deactivated, whether due to a fault or being disabled by setting the HZ MODE bit.

### **Boost Mode**

Boost Mode can be enabled if the IC is in 32-Second Mode with the OTG pin and OPA\_MODE bits as indicated in Table 16. The OTG pin ACTIVE state is 1 if OTG\_PL=1 and 0 when OTG PL=0.

If boost is active using the OTG pin, Boost Mode is initiated even if the HZ\_MODE=1. The HZ\_MODE bit overrides the OPA\_MODE bit.

**Table 16. Enabling Boost** 

OTG_EN	OTG Pin	HZ_ MODE	OPA_ MODE	BOOST
1	ACTIVE	Х	Х	Enabled
Х	Х	0	1	Enabled
X	ACTIVE	X	0	Disabled
0	Х	1	Х	Disabled
1	ACTIVE	1	1	Disabled
0	ACTIVE	0	0	Disabled

To remain in Boost Mode, the TMR\_RST must be set by the host before the  $t_{32S}$  timer times out. If  $t_{32S}$  times out in Boost Mode; the IC resets all registers, pulses the STAT pin, sets the FAULT bits to 110, and resets the BOOST bit. VBUS POR or reading R0 clears the fault condition.

### **Boost PWM Control**

The IC uses a minimum on-time and computed minimum off-time to regulate VBUS. The regulator achieves excellent transient response by employing current-mode modulation. This technique causes the regulator to exhibit a load line. During PWM Mode, the output voltage drops slightly as the input current rises. With a constant  $V_{\text{BAT}}$ , this appears as a constant output resistance.

The "droop" caused by the output resistance when a load is applied allows the regulator to respond smoothly to load transients with no undershoot from the load line. This can be seen in Figure 33 and Figure 43.

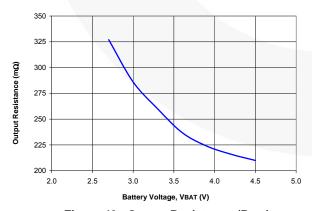


Figure 43. Output Resistance (R<sub>OUT</sub>)

 $V_{BUS}$  as a function of  $I_{LOAD}$  can be computed when the regulator is in PWM Mode (continuous conduction) as:

$$V_{OUT} = 5.07 - R_{OUT} \bullet I_{LOAD}$$
 EQ. 1

At  $V_{BAT}$ =3.3V, and  $I_{LOAD}$ =200mA,  $V_{BUS}$  would drop to:

$$V_{OLIT} = 5.07 - 0.26 \bullet 0.2 = 5.018V$$
 EQ. 1A

At  $V_{BAT}$ =2.7V, and  $I_{LOAD}$ =200mA,  $V_{BUS}$  would drop to:

$$V_{OLIT} = 5.07 - 0.327 \bullet 0.2 = 5.005V$$
 EQ. 18

#### **PFM Mode**

If  $V_{BUS} > VREF_{BOOST}$  (nominally 5.07V) when the minimum off-time has ended, the regulator enters PFM Mode. Boost pulses are inhibited until  $V_{BUS} < VREF_{BOOST}$ . The minimum on-time is increased to enable the output to pump up sufficiently with each PFM boost pulse. Therefore the regulator behaves like a constant on-time regulator, with the bottom of its output voltage ripple at 5.07V in PFM Mode.

**Table 17. Boost PWM Operating States** 

Mode	Description	Invoked When
LIN	Linear Startup	V <sub>BAT</sub> > V <sub>BUS</sub>
SS	Boost Soft-Start	V <sub>BUS</sub> < V <sub>BST</sub>
BST	Boost Operating Mode	V <sub>BAT</sub> > UVLO <sub>BST</sub> and SS Completed

### Startup

When the boost regulator is shut down, current flow is prevented from  $V_{\text{BAT}}$  to  $V_{\text{BUS}},$  as well as reverse flow from  $V_{\text{RIIS}}$  to  $V_{\text{RAT}}.$ 

#### **LIN State**

When EN rises, if  $V_{BAT}$  > UVLO<sub>BST</sub>, the regulator first attempts to bring PMID within 400mV of  $V_{BAT}$  using an internal 450mA current source from VBAT (LIN State). If PMID has not achieved  $V_{BAT}$  – 400mV after 560 $\mu$ s, a FAULT state is initiated.

#### SS State

When PMID >  $V_{BAT}$  - 400mV, the boost regulator begins switching with a reduced peak current limit of about 50% of its normal current limit. The output slews up until  $V_{BUS}$  is within 5% of its set point; at which time, the regulation loop is closed and the current limit is set to 100%.

If the output fails to achieve 95% of its set point ( $V_{BST}$ ) within 128 $\mu$ s, the current limit is increased to 100%. If the output fails to achieve 95% of its set point after this second 384 $\mu$ s period, a fault state is initiated.

#### **BST State**

This is the normal operating mode of the regulator. The regulator uses a minimum  $t_{OFF}$ -minimum  $t_{ON}$  modulation scheme. The minimum  $t_{OFF}$  is proportional to  $\frac{V_{IN}}{V_{OUT}}$ , which

keeps the regulator's switching frequency reasonably constant in CCM.  $t_{\text{ON(MIN)}}$  is proportional to  $V_{\text{BAT}}$  and is a higher value if the inductor current reached 0 before  $t_{\text{OFF(MIN)}}$  in the prior cycle.

To ensure the VBUS does not pump significantly above the regulation point, the boost switch remains off as long as  $FB > V_{RFF}$ .

### **Boost Faults**

If a BOOST fault occurs:

- 1. The STAT pin pulses.
- 2. OPA MODE bit is reset.
- 3. The power stage is in High-Impedance Mode.
- 4. The FAULT bits (REG0[2:0]) are set per Table 18.

### **Restart After Boost Faults**

If boost was enabled with the OPA\_MODE bit and OTG\_EN=0, Boost Mode can only be enabled through subsequent I<sup>2</sup>C commands since OPA\_MODE is reset on boost faults. If OTG\_EN=1 and the OTG pin is still ACTIVE (see Table 16), the boost restarts after a 5.2ms delay, as shown in Figure 44. If the fault condition persists, restart is attempted every 5ms until the fault clears or an I<sup>2</sup>C command disables the boost.

Table 18. Fault Bits During Boost Mode

Fa	ult l	Bit	Foult Description			
B2	В1	В0	Fault Description			
0	0	0	Normal (no fault)			
0	0	1	V <sub>BUS</sub> > VBUS <sub>OVP</sub>			
0	1	0	$V_{\text{BUS}}$ fails to achieve the voltage required to advance to the next state during soft-start or sustained (>50 $\mu$ s) current limit during the BST state.			
0	1	1	V <sub>BAT</sub> < UVLO <sub>BST</sub>			
1	0	0	N/A: This code does not appear.			
1	0	1	Thermal shutdown			
1	1	0	Timer fault; all registers reset.			
1	1	1	N/A: This code does not appear.			

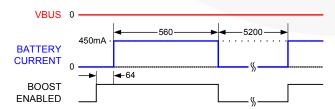


Figure 44. Boost Response Attempting to Start into V<sub>BUS</sub> Short Circuit (Times in μs)

#### **VREG Pin**

The VREG pin on FAN5400 - FAN5402 provides a voltage protected from over-voltage surges on VBUS, which can be used to run auxiliary circuits. This voltage is essentially a current-limited replica of PMID. The maximum voltage on this node is 5.9V.

FAN5403-FAN5405 provide a 1.8V regulated output on this pin, which can be disabled through  $I^2C$  by setting the DIS\_VREG bit (REG5[6]). VREG can supply up to 2mA. This circuit, which is powered from PMID, is enabled only when PMID >  $V_{BAT}$  and does not drain current from the battery. During boost,  $V_{REG}$  is off. It is also off when the HZ\_MODE bit (REG1[1])=1.

## **Monitor Register (Reg10H)**

Additional status monitoring bits enable the host processor to have more visibility into the status of the IC. The monitor bits are real-time status indicators and are not internally debounced or otherwise time qualified.

The state of the MONITOR register bits listed in High-Impedance Mode are only valid when  $V_{\text{BUS}}$  is valid.

Table 19. MONITOR Register Bit Definitions

DIT#	NAME	S	Active When	
BIT#	NAME	0	1	Active when
MONIT	OR Addre	ss 10H		•
7	ITERM CMP	V <sub>CSIN</sub> - V <sub>BAT</sub> < V <sub>ITERM</sub>	V <sub>CSIN</sub> - V <sub>BAT</sub> > V <sub>ITERM</sub>	Charging with TE=1
1	TIERW_CWP	$V_{CSIN} - V_{BAT} < 1mV$	V <sub>CSIN</sub> – V <sub>BAT</sub> > 1mV	Charging with TE=0
		V <sub>BAT</sub> < V <sub>SHORT</sub>	V <sub>BAT</sub> > V <sub>SHORT</sub>	Charging
6	VBAT_CMP	$V_{BAT} < V_{LOWV}$	$V_{BAT} > V_{LOWV}$	High-Impedance Mode
		V <sub>BAT</sub> < UVLO <sub>BST</sub>	V <sub>BAT</sub> > UVLO <sub>BST</sub>	Boosting
5	LINCHG	Linear Charging Not Enabled	Linear Charging Enabled	Charging
4	T_120	T <sub>J</sub> < 120°	T <sub>J</sub> > 120°	
3	ICHG	Charging Current Controlled by I <sub>CHARGE</sub> Control Loop	Charging Current Not Controlled by I <sub>CHARGE</sub> Control Loop	Charging
2	IBUS	I <sub>BUS</sub> Limiting Charging Current	Charge Current Not Limited by I <sub>BUS</sub>	Charging
1	VBUS_VALID	V <sub>BUS</sub> Not Valid	V <sub>BUS</sub> is Valid	V <sub>BUS</sub> > V <sub>BAT</sub>
0	CV	Constant Current Charging	Constant Voltage Charging	Charging

### I<sup>2</sup>C Interface

The FAN540X's serial interface is compatible with Standard, Fast, Fast Plus, and High-Speed Mode I<sup>2</sup>C-Bus® specifications. The FAN540X's SCL line is an input and its SDA line is a bi-directional open-drain output; it can only pull down the bus when active. The SDA line only pulls LOW during data reads and when signaling ACK. All data is shifted in MSB (bit 7) first.

### **Slave Address**

Table 20. I<sup>2</sup>C Slave Address Byte

Part Types	7	6	5	4	3	2	1	0
FAN5400-FAN5404	1	1	0	1	0	1	1	$R/\overline{W}$
FAN5405	1	1	0	1	0	1	0	$R/\overline{W}$

In hex notation, the slave address assumes a 0 LSB. The hex slave address for the FAN5405 is D4H and is D6H for all other parts in the family.

### **Bus Timing**

As shown in Figure 45, data is normally transferred when SCL is LOW. Data is clocked in on the rising edge of SCL. Typically, data transitions shortly at or after the falling edge of SCL to allow ample time for the data to set up before the next SCL rising edge.

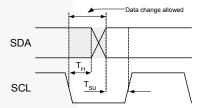


Figure 45. Data Transfer Timing

Each bus transaction begins and ends with SDA and SCL HIGH. A transaction begins with a START condition, which is defined as SDA transitioning from 1 to 0 with SCL HIGH, as shown in Figure 46.

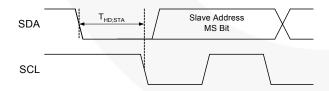


Figure 46. Start Bit

A transaction ends with a STOP condition, which is defined as SDA transitioning from 0 to 1 with SCL HIGH, as shown in Figure 47.

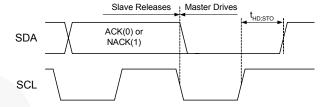


Figure 47. Stop Bit

During a read from the FAN540X (Figure 50), the master issues a Repeated Start after sending the register address and before resending the slave address. The Repeated Start is a 1-to-0 transition on SDA while SCL is HIGH, as shown in Figure 48.

### **High-Speed (HS) Mode**

The protocols for High-Speed (HS), Low-Speed (LS), and Fast-Speed (FS) Modes are identical except the bus speed for HS Mode is 3.4MHz. HS Mode is entered when the bus master sends the HS master code 00001XXX after a start condition. The master code is sent in Fast or Fast Plus Mode (less than 1MHz clock); slaves do not ACK this transmission.

The master then generates a repeated start condition (Figure 48) that causes all slaves on the bus to switch to HS Mode. The master then sends I<sup>2</sup>C packets, as described above, using the HS Mode clock rate and timing.

The bus remains in HS Mode until a stop bit (Figure 47) is sent by the master. While in HS Mode, packets are separated by repeated start conditions (Figure 48).

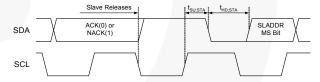


Figure 48. Repeated Start Timing

### **Read and Write Transactions**

The figures below outline the sequences for data read and write. Bus control is signified by the shading of the packet,

write.	ous (	COLLIGIO	s signinie	u by	uie s	silaulily	or the	packet,
defined	as	Maste	r Drives E	Bus	and	Slav	e Drives	Bus
		esses	and	data		are	MSB	first.

Table 21. Bit Definitions for Figure 49, Figure 50

	• • •
Symbol	Definition
S	START, see Figure 46.
А	ACK. The slave drives SDA to 0 to acknowledge the preceding packet.
A	NACK. The slave sends a 1 to NACK the preceding packet.
R	Repeated START, see Figure 48
Р	STOP, see Figure 47



Figure 49. Write Transaction



Figure 50. Read Transaction

## **Register Descriptions**

The FAN5400-FAN5402 have seven user-accessible registers; the FAN5403-05 have an additional two registers, as defined in Table 22.

Table 22. I<sup>2</sup>C Register Address

IC	Register		Address Bits								
IC	Name	REG#	7	6	5	4	3	2	1	0	
	CONTROL0	0	0	0	0	0	0	0	0	0	
	CONTROL1	1	0	0	0	0	0	0	0	1	
	OREG	2	0	0	0	0	0	0	1	0	
ALL	IC_INFO	03 or 3BH	0	0	0	0	0	0	1	1	
	IBAT	4	0	0	0	0	0	1	0	0	
FAN5403-FAN5405	SP_CHARGER	5	0	0	0	0	0	1	0	1	
FAIND405-FAIND405	SAFETY	6	0	0	0	0	0	1	1	0	
ALL	MONITOR	10H	0	0	0	0	1	0	1	0	

## **Table 23. Register Bit Definitions**

This table defines the operation of each register bit for all IC versions. Default values are in **bold** text.

Bit	Name	Value	Туре		Description		
CONT	ROL0			Register Address: 00 Default Value=X1XX 0XXX			
7	TMR_RST	1	W	Writing a 1 resets the t <sub>32S</sub> t	imer; writing a 0 has no effect		
′	OTG	'	R	Returns the OTG pin level	(1=HIGH)		
6	EN STAT	0	R/W	Prevents STAT pin from go enunciate faults	revents STAT pin from going LOW during charging; STAT pin still pulses to nunciate faults		
		1		Enables STAT pin LOW v	when IC is charging		
		00	R	Ready			
F. 4	STAT	01		Charge in progress			
5:4	SIAI	10		Charge done			
		11		Fault			
3	BOOST	0	R	IC is not in Boost Mode			
3	ВООЗТ	1		C is in Boost Mode			
2:0	FAULT		R	Fault status bits: for Charg	e Mode, see Table 13; for Boost Mode: see Table 18		

Table 23. Register Bit Definitions (Continued)

Bit	Name	Value	Туре	Description				
CONT	ROL1			Register Address: 01	Default Value=0011 0000 (30H)			
7:6	I <sub>INLIM</sub>		R/W	Input current limit, see Table 7				
		00	R/W	3.4V				
	.,,	01		3.5V				
5:4	$V_{LOWV}$	10		3.6V	Weak battery voltage threshold			
		11		3.7V				
_		0	R/W	Disable charge current termination				
3	TE	1		Enable charge current termination				
		0	R/W	Charger enabled				
2	CE	1		Charger disabled				
	LIZ MODE	0	R/W	Not High-Impedance Mode				
1	HZ_MODE	1		High-Impedance Mode	0 7 11 10			
0	ODA MODE	0	R/W	Charge Mode	See Table 16			
0	OPA_MODE	1		Boost Mode				
OREG		y		Register Address: 02	Default Value=0000 1010 (0AH)			
7:2	OREG		R/W	Charger output "float" voltage; prograr increments; defaults to 000010 (3.54				
		0	R/W	OTG pin active LOW				
1	OTG_PL	1		OTG pin active HIGH				
	OTO EN	0	R/W	Disables OTG pin				
0	OTG_EN	1		Enables OTG pin				
IC_INF	<b>-</b> 0			Register Address: 03 or 3B	Default Value=100X XXXX			
7:5	Vendor Code	100	R	Identifies Fairchild Semiconductor as	the IC supplier			
4:3	PN		R	Part number bits, see the Ordering Int	fo on page 1			
2:0	REV		R	IC Revision, revision 1.X, where X is t	he decimal of these three bits			
IBAT				Register Address: 04	Default Value=1000 1001 (89H)			
7	RESET	1	W	Writing a 1 resets charge parameters, except the Safety register (Reg6), to their defaults: writing a 0 has no effect; read returns 1				
6:4	IOCHARGE	Table 5	R/W	Programs the maximum charge current, see Table 5				
3	Reserved	1	R	Unused				
2:0	ITERM	Table 6	R/W	Sets the current used for charging terr	mination, see Table 6			

Table 23. Register Bit Definitions (Continued)

SP_CHARGER (FAN5403 - FAN5405)				Register Address: 05 Default Value=001X X100		
7	Reserved	0	R	Unused		
6	DIS_VREG	0	R/W	1.8V regulator is ON		
		1		1.8V regulator is OFF		
5	IO_LEVEL	0	R/W	Output current is controlled by IOCHARGE bits		
		1		Voltage across $R_{SENSE}$ for output current control is set to 22.1mV (325mA for $R_{SENSE}$ =68m $\Omega$ , 221mA for 100m $\Omega$ )		
4	SP	0	R	Special charger is not active (V <sub>BUS</sub> is able to stay above V <sub>SP</sub> )		
		1		Special charger has been detected and V <sub>BUS</sub> is being regulated to V <sub>SP</sub>		
3	EN_LEVEL	0	R	DISABLE pin is LOW		
		1		DISABLE pin is HIGH		
2:0	VSP	Table 8	R/W	Special charger input regulation voltage, see Table 8		
SAFETY (FAN5403 – FAN5405)				Register Address: 06 Default Value=0100 0000 (40H)		
7	Reserved	0	R	Bit disabled and always returns 0 when read back		
6:4	ISAFE	Table 9	R/W	Sets the maximum I <sub>OCHARGE</sub> value used by the control circuit, see Table 9		
3:0	VSAFE	Table 10	R/W	Sets the maximum V <sub>OREG</sub> used by the control circuit, see <i>Table 10</i>		
MONITOR				Register Address: 10H (16) See Table 19		
7	ITERM_CMP		R	ITERM comparator output, 1 when VRSENSE > ITERM reference		
6	VBAT_CMP		R	Output of VBAT comparator		
5	LINCHG	See Table 19	R	30mA linear charger ON		
4	T_120		R	Thermal regulation comparator; when=1 and T_145=0, the charge current is limited to 22.1mV across $R_{\text{SENSE}}$		
3	ICHG		R	0 indicates the I <sub>CHARGE</sub> loop is controlling the battery charge current		
2	IBUS		R	0 indicates the I <sub>BUS</sub> (input current) loop is controlling the battery charge current		
1	VBUS_VALID		R	1 indicates V <sub>BUS</sub> has passed validation and is capable of charging		
0	CV		R	1 indicates the constant-voltage loop (OREG) is controlling the charger and all current limiting loops have released		

## **PCB Layout Recommendations**

Bypass capacitors should be placed as close to the IC as possible. In particular, the total loop length for CMID should be minimized to reduce overshoot and ringing on the SW, PMID, and VBUS pins. All power and ground pins must be

routed to their bypass capacitors using top copper if possible. Copper area connecting to the IC should be maximized to improve thermal performance.

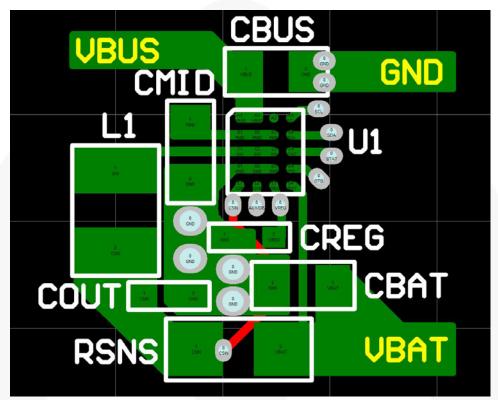


Figure 51. PCB Layout Recommendations

## **Physical Dimensions**

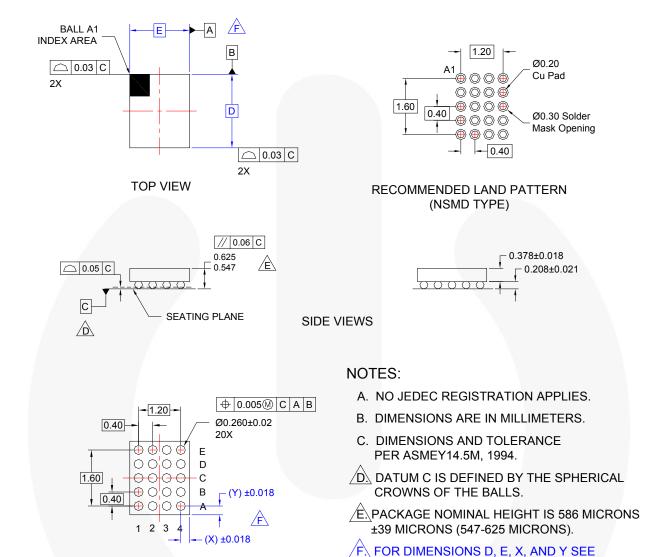


Figure 52. 20-Ball WLCSP, 4X5 Array, 0.4mm Pitch, 250µm Ball

PRODUCT DATASHEET.

G. DRAWING FILNAME: MKT-UC020AArev2.

## **Product-Specific Dimensions**

**BOTTOM VIEW** 

Product	D	E	Х	Υ
FAN540XUCX	1.960 <u>+</u> 0.030	1.870 <u>+</u> 0.030	0.335	0.180

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